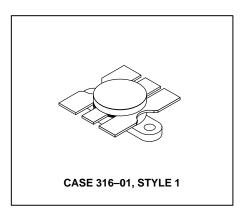
# The RF Line NPN Silicon RF Power Transistor

The MRF247 is designed for 12.5 Volt VHF large—signal amplifier applications in industrial and commercial FM equipment operating to 175 MHz.

- Specified 12.5 Volt, 175 MHz Characteristics —
   Output Power = 75 Watts
   Power Gain = 7.0 dB Min
   Efficiency = 55% Min
- Characterized With Series Equivalent Large-Signal Impedance Parameters
- Internal Matching Network Optimized for Minimum Gain Frequency Slope Response Over the Range 136 to 175 MHz
- Load Mismatch Capability at Rated Pout and Supply Voltage

# **MRF247**

75 W, 175 MHz CONTROLLED Q RF POWER TRANSISTOR NPN SILICON



### **MAXIMUM RATINGS**

| Rating   | Symbol           | Value       | Unit          |
|--|------------------|-------------|---------------|
| Collector–Emitter Voltage  | VCEO             | 18          | Vdc           |
| Collector–Base Voltage   | VCBO             | 36          | Vdc           |
| Emitter-Base Voltage   | VEBO             | 4.0         | Vdc           |
| Collector Current — Peak   | IC               | 20          | Adc           |
| Total Device Dissipation @ T <sub>C</sub> = 25°C (1) Derate above 25°C | PD               | 250<br>1.43 | Watts<br>W/°C |
| Storage Temperature Range  | T <sub>stg</sub> | -65 to +150 | °C            |

### THERMAL CHARACTERISTICS

| Characteristic                           | Symbol          | Max | Unit |
|--|-----------------|-----|------|
| Thermal Resistance, Junction to Case (2) | $R_{\theta JC}$ | 0.7 | °C/W |

### **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub> = 25°C unless otherwise noted.)

| Characteristic  | Symbol   | Min | Тур | Max | Unit |  |
|---|----------|-----|-----|-----|------|--|
| OFF CHARACTERISTICS   |          |     |     |     |      |  |
| Collector–Emitter Breakdown Voltage (I <sub>C</sub> = 100 mAdc, I <sub>B</sub> = 0) | V(BR)CEO | 18  | _   | _   | Vdc  |  |
| Collector–Emitter Breakdown Voltage (IC = 50 mAdc, VBE = 0)                         | V(BR)CES | 36  | _   | _   | Vdc  |  |
| Emitter–Base Breakdown Voltage (I <sub>E</sub> = 10 mAdc, I <sub>C</sub> = 0)       | V(BR)EBO | 4.0 | _   | _   | Vdc  |  |

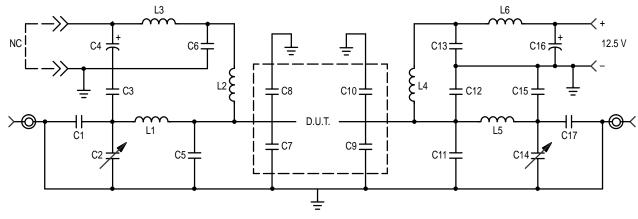
- (1) This device is designed for RF operation. The total device dissipation rating applies only when the device is operated as an RF amplifier.
- (2) Thermal Resistance is determined under specified RF operating conditions by infrared measurement techniques.

#### REV 1



## **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub> = 25°C unless otherwise noted.)

| Characteristic   | Symbol                | Min                            | Тур | Max | Unit |
|--|-----------------------|--------------------------------|-----|-----|------|
| ON CHARACTERISTICS   | •                     |                                |     |     |      |
| DC Current Gain<br>(I <sub>C</sub> = 5.0 Adc, V <sub>CE</sub> = 5.0 Vdc)   | h <sub>FE</sub> 10 75 |                                | 150 | _   |      |
| DYNAMIC CHARACTERISTICS  | •                     | •                              |     | •   |      |
| Output Capacitance<br>(V <sub>CB</sub> = 15 Vdc, I <sub>E</sub> = 0, f = 1.0 MHz)  | C <sub>ob</sub>       | _                              | 235 | 300 | pF   |
| FUNCTIONAL TESTS   |                       |                                |     |     |      |
| Common–Emitter Amplifier Power Gain (V <sub>CC</sub> = 12.5 Vdc, P <sub>Out</sub> = 75 Watts, f = 175 MHz)               | GPE                   | 7.0                            | 8.5 | _   | dB   |
| Collector Efficiency<br>(V <sub>CC</sub> = 12.5 Vdc, P <sub>Out</sub> = 75 Watts, f = 175 MHz)                           | η                     | 55                             | 60  | _   | %    |
| Load Mismatch<br>(V <sub>CC</sub> = 12.5 Vdc, P <sub>Out</sub> = 75 Watts, f = 175 MHz,<br>VSWR = 30:1 All Phase Angles) | Ψ                     | No Degradation in Output Power |     |     |      |



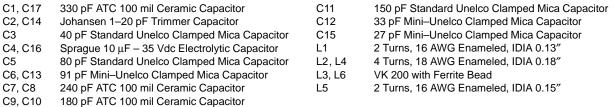


Figure 1. Output Power versus Input Power

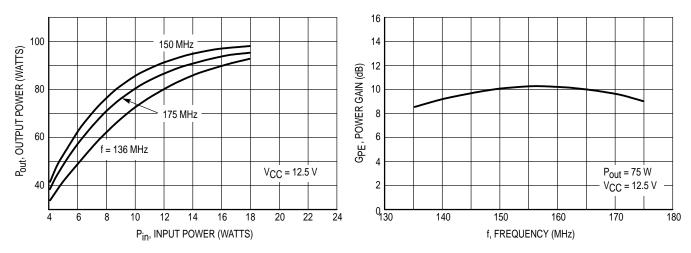


Figure 2. Output Power versus Input Power

Figure 3. Power Gain versus Frequency

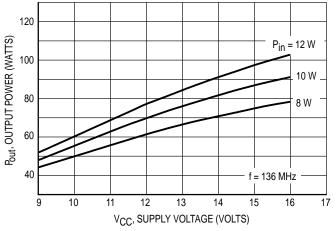


Figure 4. Output Power versus Supply Voltage

Figure 5. Output Power versus Supply Voltage

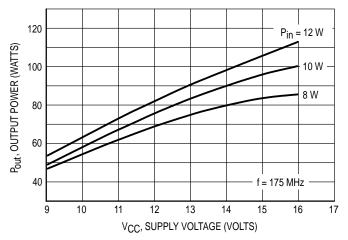


Figure 6. Output Power versus Supply Voltage

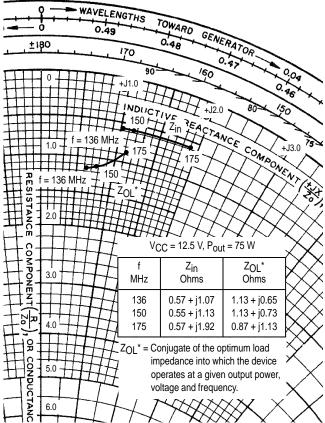
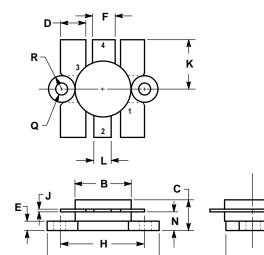


Figure 7. Series Equivalent Impedances

MOTOROLA RF DEVICE DATA

MRF247

#### PACKAGE DIMENSIONS



1. FLANGE IS ISOLATED IN ALL STYLES.

|     | INC   | HES   | MILLIN | IETERS |
|-----|-------|-------|--------|--------|
| DIM | MIN   | MAX   | MIN    | MAX    |
| Α   | 24.38 | 25.14 | 0.960  | 0.990  |
| В   | 12.45 | 12.95 | 0.490  | 0.510  |
| С   | 5.97  | 7.62  | 0.235  | 0.300  |
| D   | 5.33  | 5.58  | 0.210  | 0.220  |
| E   | 2.16  | 3.04  | 0.085  | 0.120  |
| F   | 5.08  | 5.33  | 0.200  | 0.210  |
| Н   | 18.29 | 18.54 | 0.720  | 0.730  |
| J   | 0.10  | 0.15  | 0.004  | 0.006  |
| K   | 10.29 | 11.17 | 0.405  | 0.440  |
| L   | 3.81  | 4.06  | 0.150  | 0.160  |
| N   | 3.81  | 4.31  | 0.150  | 0.170  |
| Q   | 2.92  | 3.30  | 0.115  | 0.130  |
| R   | 3.05  | 3.30  | 0.120  | 0.130  |
| U   | 11.94 | 12.57 | 0.470  | 0.495  |

STYLE 1: PIN 1. EMITTER

2. COLLECTOR 3. EMITTER

4. BASE

**CASE 316-01 ISSUE D** 

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MRF247/D